

MT9P006

CMOS Image Sensor, 5 MP, 1/2.5"

Product Overview

For complete documentation, see the data sheet.

ON Semiconductor's focus on pixel performance excellence provides the foundation for this sensor's exceptional image quality with superior color accuracy, low-light sensitivity, and low noise level. This cost-effective CMOS imaging solution enables high speed image capture capabilities, and includes variable functions, including gain, frame rate, and exposure while maintaining low power consumption.

Applications

Security

Part Electrical Specifications												
Product	Pricing (\$/Unit)	Complian ce	Status	Туре	Megapi xels	Frame Rate (fps)	Optical Format	Shutter Type	Pixel Size (µm)	Output Interfac e	Color	Packag e Type
MT9P006l12ST CU-DP		РЬ Н	Active	CMOS	5	15	1/2.5 inch	Electron ic Rolling	2.2 x 2.2	Parallel	Bayer Color	ILCC- 48
MT9P006l12ST CU-DP1		РЬ Н	Active	CMOS	5	15	1/2.5 inch	Electron ic Rolling	2.2 x 2.2	Parallel	Bayer Color	ILCC- 48
MT9P006l12ST CU-DR		Pb H	Active	CMOS	5	15	1/2.5 inch	Electron ic Rolling	2.2 x 2.2	Parallel	Bayer Color	ILCC- 48
MT9P006I12ST CU-DR1		Pb (f)	Active	CMOS	5	15	1/2.5 inch	Electron ic Rolling	2.2 x 2.2	Parallel	Bayer Color	ILCC- 48